

# -100mA / -50V Digital transistors (with built-in resistors)

## DTA115TM / DTA115TE / DTA115TUA / DTA115TKA / DTA115TSA

### ●Applications

Inverter, Interface, Driver

### ●Features

- 1) Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors.
- 2) The bias resistors consist of thin-film resistors with complete isolation to allow positive biasing of the input, and parasitic effects are almost completely eliminated.
- 3) Only the on / off conditions need to be set for operation, making the device design easy.
- 4) Higher mounting densities can be achieved.

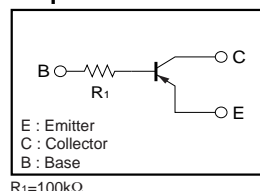
### ●Structure

PNP epitaxial planar silicon transistor  
(Resistor built-in type)

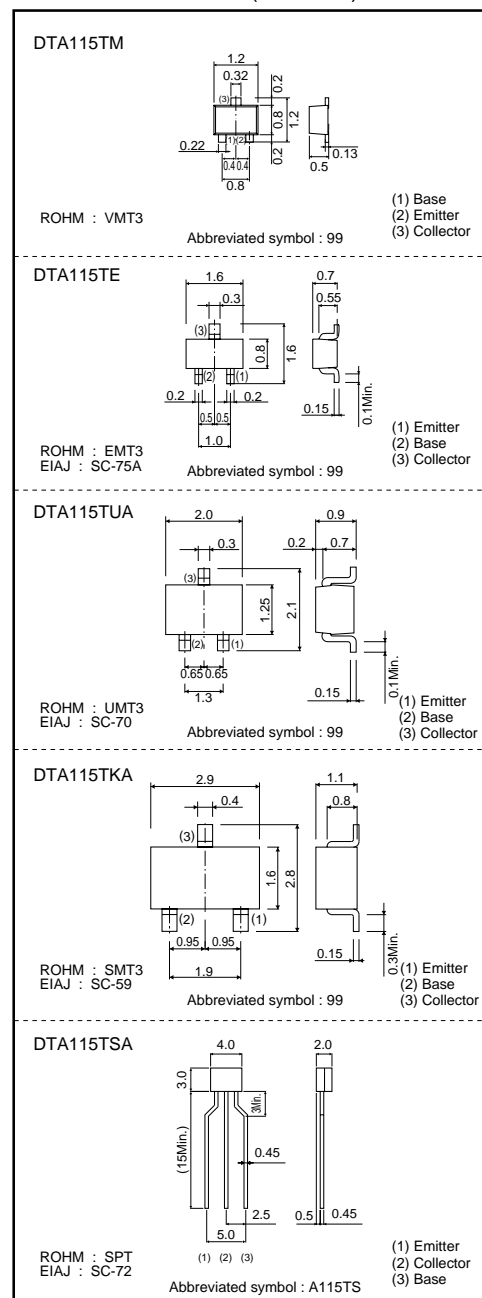
### ●Packaging specifications

Package	VMT3	EMT3	UMT3	SMT3	SPT
Packaging type	Taping	Taping	Taping	Taping	Taping
Code	T2L	TL	T106	T146	TP
Basic ordering unit (pieces)	8000	3000	3000	3000	5000
Part No.					
DTA115TM	○	—	—	—	—
DTA115TE	—	○	—	—	—
DTA115TUA	—	—	○	—	—
DTA115TKA	—	—	—	○	—
DTA115TSA	—	—	—	—	○

### ●Equivalent circuit



### ●External dimensions (Unit : mm)



# DTA115TM / DTA115TE / DTA115TUA / DTA115TKA / DTA115TSA

## Transistors

### ●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	$V_{CBO}$	-50	V
Collector-emitter voltage	$V_{CEO}$	-50	V
Emitter-base voltage	$V_{EBO}$	-5	V
Collector current	$I_C$	-100	mA
Collector power dissipation	DTA115TM / DTA115TE	150	mW
	DTA115TUA / DTA115TKA	200	
	DTA115TSA	300	
Junction temperature	$T_j$	150	°C
Storage temperature	$T_{stg}$	-55 to +150	°C

### ●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	$BV_{CBO}$	-50	—	—	V	$I_C = -50\mu A$
Collector-emitter breakdown voltage	$BV_{CEO}$	-50	—	—	V	$I_C = -1mA$
Emitter-base breakdown voltage	$BV_{EBO}$	-5	—	—	V	$I_E = -50\mu A$
Collector cutoff current	$I_{CBO}$	—	—	-0.5	$\mu A$	$V_{CB} = -50V$
Emitter cutoff current	$I_{EBO}$	—	—	-0.5	$\mu A$	$V_{EB} = -4V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	—	—	-0.3	V	$I_C/I_B = -1mA/-0.1mA$
DC current transfer ratio	$h_{FE}$	100	250	600	—	$I_C = -1mA, V_{CE} = -5V$
Input resistance	$R_1$	70	100	130	k $\Omega$	—
Transition frequency	$f_T$ *	—	250	—	MHz	$V_{CE} = -10V, I_E = 5mA, f = 100MHz$

\*Characteristics of built-in transistor

### ●Electrical characteristics curves

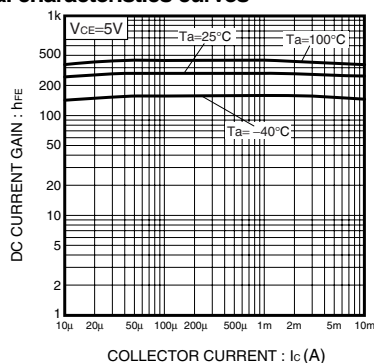


Fig.1 DC current gain  
vs. Collector current

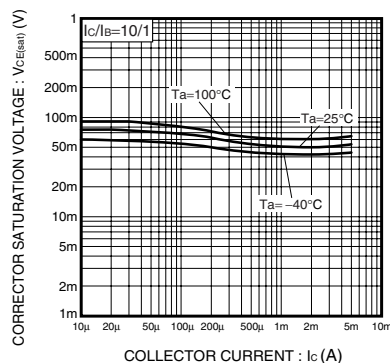


Fig.2 Collector-Emitter saturation voltage  
vs. Collector current

### Notes

- No technical content pages of this document may be reproduced in any form or transmitted by any means without prior permission of ROHM CO.,LTD.
- The contents described herein are subject to change without notice. The specifications for the product described in this document are for reference only. Upon actual use, therefore, please request that specifications to be separately delivered.
- Application circuit diagrams and circuit constants contained herein are shown as examples of standard use and operation. Please pay careful attention to the peripheral conditions when designing circuits and deciding upon circuit constants in the set.
- Any data, including, but not limited to application circuit diagrams information, described herein are intended only as illustrations of such devices and not as the specifications for such devices. ROHM CO.,LTD. disclaims any warranty that any use of such devices shall be free from infringement of any third party's intellectual property rights or other proprietary rights, and further, assumes no liability of whatsoever nature in the event of any such infringement, or arising from or connected with or related to the use of such devices.
- Upon the sale of any such devices, other than for buyer's right to use such devices itself, resell or otherwise dispose of the same, no express or implied right or license to practice or commercially exploit any intellectual property rights or other proprietary rights owned or controlled by
- ROHM CO., LTD. is granted to any such buyer.
- Products listed in this document are no antiradiation design.

The products listed in this document are designed to be used with ordinary electronic equipment or devices (such as audio visual equipment, office-automation equipment, communications devices, electrical appliances and electronic toys).

Should you intend to use these products with equipment or devices which require an extremely high level of reliability and the malfunction of which would directly endanger human life (such as medical instruments, transportation equipment, aerospace machinery, nuclear-reactor controllers, fuel controllers and other safety devices), please be sure to consult with our sales representative in advance.

#### About Export Control Order in Japan

Products described herein are the objects of controlled goods in Annex 1 (Item 16) of Export Trade Control Order in Japan.

In case of export from Japan, please confirm if it applies to "objective" criteria or an "informed" (by MITI clause) on the basis of "catch all controls for Non-Proliferation of Weapons of Mass Destruction.